



#### Communication

# Nitrogen-Doped Graphene Quantum Dots with Oxygen-rich Functional Groups

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The electrochemical process for the formation of N GQDs is shown in Figures S1 and S  $\,\iota$  Just like the oxidation of other car bon materials by an oxidant

ods/. Comparing with GQDs however N GQDs exhibit a broader D band suggesting that the intercalation of N atoms into the con jugated carbon backbone has led to somewhat disordered struc tures/.

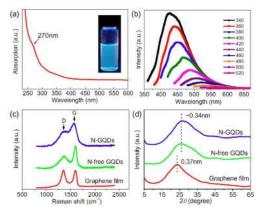


Figure 3. a and b UV vis absorption and photoluminescence PL spectra of N GQDs in water respectively. c Raman spectra and d XRD patterns of the original graphene film the N free and N GQDs. Inset in a is a photo of the N GQD solution in water under 'nm UV irradiation.

Figure d shows typical XRD profiles for the original graphene film and the as prepared N free and N GQDst Just like their N free counterparts the N GQDs show a broader diffraction peak at around 2° which is substantially higher than that of the gra phene film ca.  $2l^{\circ} l$  The more compact interlayer spacing ca. 0.4 nm probed by XRD for N GQDs than the original graphene film ca. 04 \_ nm is consistent with the TEM observation Figure **5** L The reduced interlayer spacing in N GQDs could be attrib uted to the effective  $\pi$   $\pi$  stacking of tiny graphenes with few struc ture defects Figure 2 ! On the other hand the possible formation of hydrogen bonding between the O containing functional groups surrounding the edges of the graphene layers in N GQDs Figures a S and S may further facilitate the compact stacking of graphene layers Figure \$ \( \psi\$ t It is also worth to note that N GQDs thus prepared do not show any diffractions in the region of ca. 10° b characteristic of graphene oxides evidently indicating that the N GQDs are different from graphene oxide though both contain oxygen enriched functional groups Figure 2

N doped carbon nanomaterials such as N CNTs and N graphene<sup>1</sup> have been demonstrated to hold promise as metal free electrocatalysts in replacing the commercially available Pt based catalyst for ORRL Apart from their unique luminescent properties N GQDs are also expected to possess the electrocatalytic activi ties for ORR! To avoid any possible effect of the glassy carbon GC base electrode Figure S9 we used a large area and electri cally conductive graphene assembly to support the N GQD as ORR catalysts! The graphene supported N GQDs GQDs graphene were prepared by hydrothermal treatment of the suspension of well dispersed graphene oxides with N GQDs Figure S10 t This mild process ensured the formation of N GQD graphene assemblies without acutely changing the intrinsi cally chemical nature of N GQDs Figures S11 S1 2 The N GQD graphene film Figure S1 thus formed was demonstrated to exhibit a good conductivity of ca. 4 0 S cm and superior elec trocatalytic ability for ORR see below &

Figures 4 a and b depict CVs for O<sub>2</sub> reduction on the N GQD graphene in comparison with a commercial Pt C catalyst

Owt% platinum on carbon black \( \) Sim \( \frac{1}{2} \) \( \frac

In summary we have developed a simple yet effective electro chemical strategy to generate N doped GQDs with O rich func tional groups which show unique optoelectronic features distinc tive from their N free counterparts! Supported by graphene sheets N GQDs were demonstrated to possess superior electrocatalytic ability. Apart from the use of N GQDs as metal free catalyst for ORR their unique luminescent properties indicate potentials for bioimaging and light emitting diodes among many other potential applications<sub>L</sub>

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Supporting Information! The experimental details for prepara tion of N GQDs N GQD graphenes electrode fabrication re lated characterization and supplementary results and discussion. This material is available free of charge via the Internet at http/pubslacslorg/

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